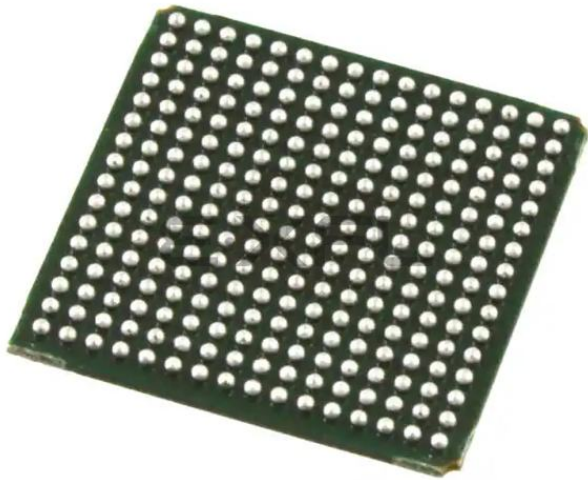




Welcome to [E-XFL.COM](https://www.e-xfl.com)

Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	-
Number of Logic Elements/Cells	2704
Total RAM Bits	113664
Number of I/O	160
Number of Gates	210000
Voltage - Supply	2.3V ~ 3.6V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 105°C (TJ)
Package / Case	256-BGA
Supplier Device Package	256-FPBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lfx200eb-04fn256i



Product Line	Ordering Part Number	Product Status	Reference PCN
LFX500B	LFX500B-03F516C	Discontinued	PCN#09-10
	LFX500B-04F516C		
	LFX500B-05F516C		
	LFX500B-03F900C		
	LFX500B-03FN900C		
	LFX500B-04F900C		
	LFX500B-04FN900C		
	LFX500B-05F900C		
	LFX500B-05FN900C		
LFX500C	LFX500C-03F516C	Discontinued	PCN#09-10
	LFX500C-04F516C		
	LFX500C-03F900C		
	LFX500C-03FN900C		
	LFX500C-04F900C		
	LFX500C-04FN900C		
LFX1200B	LFX1200B-03FE680C	Discontinued	PCN#03A-10
	LFX1200B-04FE680C		
	LFX1200B-05FE680C		
	LFX1200B-03F900C		
	LFX1200B-04F900C		
	LFX1200B-05F900C		
LFX1200C	LFX1200C-03FE680C	Discontinued	PCN#03A-10
	LFX1200C-04FE680C		
	LFX1200C-03F900C		
	LFX1200C-04F900C		
LFX125EB	LFX125EB-03F256C	Active / Orderable	
	LFX125EB-03FN256C		
	LFX125EB-04F256C		
	LFX125EB-04FN256C		
	LFX125EB-05F256C		
	LFX125EB-05FN256C		
	LFX125EB-03F256I		
	LFX125EB-03FN256I		
	LFX125EB-04F256I	Discontinued	PCN#09-10
	LFX125EB-04FN256I		
	LFX125EB-03F516C		
	LFX125EB-04F516C		
	LFX125EB-05F516C		
	LFX125EB-03F516I		
	LFX125EB-04F516I		
LFX125EC	LFX125EC-03F256C	Discontinued	PCN#09-10
	LFX125EC-03FN256C		
	LFX125EC-04F256C		
	LFX125EC-04FN256C		
	LFX125EC-03F256I		
	LFX125EC-03FN256I		

■ Non-volatile, Infinitely Reconfigurable

- Instant-on - Powers up in microseconds via on-chip E²CMOS® based memory
- No external configuration memory
- Excellent design security, no bit stream to intercept
- Reconfigure SRAM based logic in milliseconds

■ High Logic Density for System-level Integration

- 139K to 1.25M functional gates
- 160 to 496 I/O
- 1.8V, 2.5V, and 3.3V V_{CC} operation
- Up to 414Kb sysMEM™ embedded memory

■ High Performance Programmable Function Unit (PFU)

- Four LUT-4 per PFU supports wide and narrow functions
- Dual flip-flops per LUT-4 for extensive pipelining
- Dedicated logic for adders, multipliers, multiplexers, and counters

■ Flexible Memory Resources

- Multiple sysMEM Embedded RAM Blocks
 - Single port, Dual port, and FIFO operation
- 64-bit distributed memory in each PFU
 - Single port, Double port, FIFO, and Shift Register operation

■ Flexible Programming, Reconfiguration, and Testing

- Supports IEEE 1532 and 1149.1

- Microprocessor configuration interface
- Program E²CMOS while operating from SRAM

■ Eight sysCLOCK™ Phase Locked Loops (PLLs) for Clock Management

- True PLL technology
- 10MHz to 320MHz operation
- Clock multiplication and division
- Phase adjustment
- Shift clocks in 250ps steps

■ sysIO™ for High System Performance

- High speed memory support through SSTL and HSTL
- Advanced buses supported through PCI, GTL+, LVDS, BLVDS, and LVPECL
- Standard logic supported through LVTTTL, LVCMOS 3.3, 2.5 and 1.8
- 5V tolerant I/O for LVCMOS 3.3 and LVTTTL interfaces
- Programmable drive strength for series termination
- Programmable bus maintenance

■ Two Options Available

- High-performance sysHSI (standard part number)
- Low-cost, no sysHSI ("E-Series")

■ sysHSI™ Capability for Ultra Fast Serial Communications

- Up to 800Mbps performance
- Up to 20 channels per device
- Built in Clock Data Recovery (CDR) and Serialization and De-serialization (SERDES)

Table 1. ispXPGA Family Selection Guide

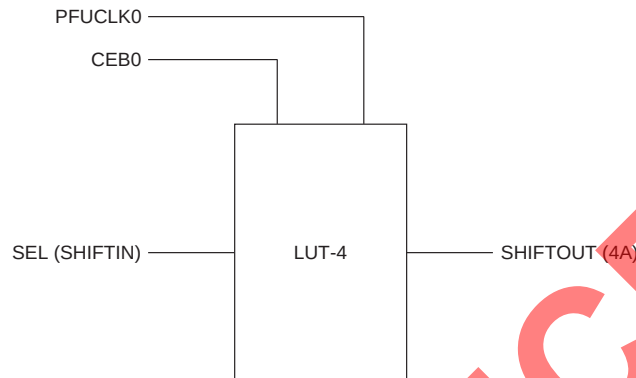
	ispXPGA 125/E	ispXPGA 200/E	ispXPGA 500/E	ispXPGA 1200/E ³
Functional Gates	139K	210K	476K	1.25M
PFUs	484	676	1764	3844
LUT-4s	1936	2704	7056	15376
Logic FFs	3.8K	5.4K	14.1K	30.7K
sysMEM Memory	92K	111K	184K	414K
Distributed Memory	30K	43K	112K	246K
EBR	20	24	40	90
sysHSI Channels ¹	4	8	12	20
User I/O	160/176	160/208	336	496
Packaging	256 fpBGA 516 fpBGA ²	256 fpBGA 516 fpBGA ²	516 fpBGA ² 900 fpBGA	680 fpSBGA 900 fpBGA

1. "E-Series" does not support sysHSI.

2. FH516 package was converted to F516 via [PCN #09A-08](#).

3. Discontinued via [PCN #03A-10](#).

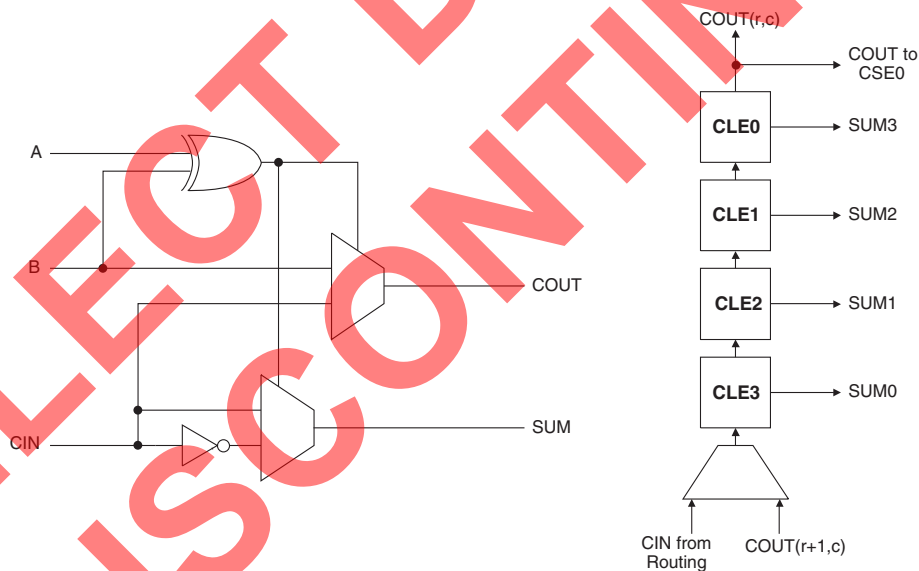
Figure 4. LUT in Shift Register Mode



Carry Chain Generator

The Carry Chain Generator is useful for implementing high-speed arithmetic functions. The CCG consists of a two-input XOR gate whose carryout can be cascaded with the input of the adjacent CCG. As shown in Figure 5, the carryin signal feeds CLE3 of the PFU and is propagated through CLE2 and CLE1 before reaching CLE0. The sum output of the CCG can be fed to the CSE through the WLG. The carryout must propagate to CLE0 for use outside the PFU. The carryout from the PFU can feed the W0 input of CSE0. The CCG also helps to effectively implement wider functions by using its logic elements to expand the capabilities of the LUT-4.

Figure 5. Carry Chain Generator



Wide Logic Generator

The WLG contains the logic necessary to implement wide gate functions. This is made up of a set of multiplexers that are located between the CLE and the CSE. The WLG helps in enhancing the wide gating capability of the PFU. The outputs of each CLE can be cascaded in the WLG to build wide gating functions. Wide multiplexing functions are also possible with a similar use of the WLG. Figure 6 illustrates the WLG.

The second type of interface implemented is the terminated, single-ended interface standard. This group of interfaces includes different versions of SSTL and HSTL interfaces along with CTT, and GTL+. Usage of these particular I/O interfaces requires an additional V_{REF} signal. At the system level a termination voltage, V_{TT} , is also required. Typically an output will be terminated to V_{TT} at the receiving end of the transmission line it is driving.

The third type of interface standards are the differential standards LVDS, BLVDS, and LVPECL. The differential standards require two I/O pins to create the differential pair. The logic level is determined by the difference in the two signals. Table 6 lists how these interface standards are implemented in the ispXPGA devices.

For more information on sysIO capability, refer to TN1000, [sysIO Usage Guidelines for Lattice Devices](#).

Figure 19. sysIO Banks per Device

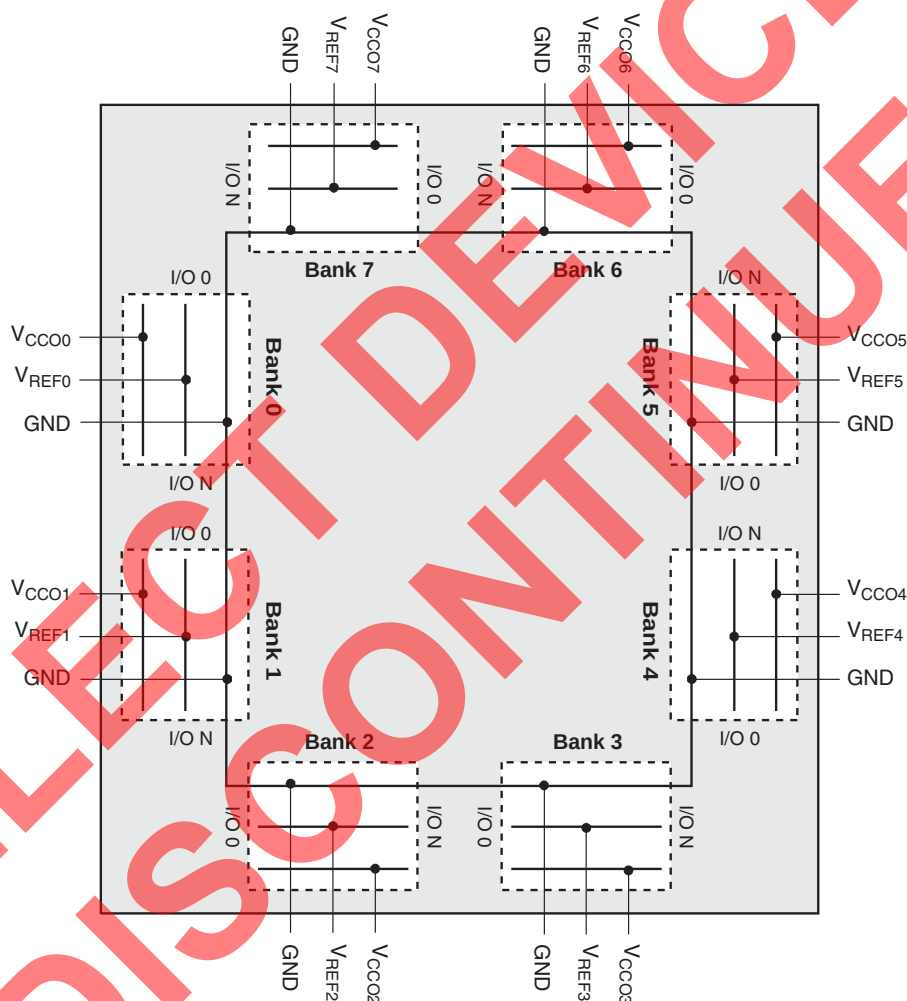


Table 4. Number of I/Os per Bank

Device	Max. Number of I/Os per Bank (N)
XPGA 1200	62
XPGA 500	42
XPGA 200	26
XPGA 125	22

DC Electrical Characteristics

Over Recommended Operating Conditions

Symbol	Parameter	Condition	Min	Typ	Max	Units
I_{IL}, I_{IH}^1	Input or I/O Low Leakage	$0 \leq V_{IN} < (V_{CCO} - 0.2V)$	—	—	10	μA
		$(V_{CCO} - 0.2V) \leq V_{IN} \leq 3.6V$	—	—	300	μA
I_{IH}^2	Input High Leakage Current	$3.6V < V_{IN} \leq 5.5V$ and $3.0V \leq V_{CCO} \leq 3.6V$	—	—	3	mA
I_{PU}	I/O Active Pull-up Current	$0 \leq V_{IN} \leq 0.7 V_{CCO}$	-30	—	-150	μA
I_{PD}	I/O Active Pull-down Current	$V_{IL} (MAX) \leq V_{IN} \leq V_{IH} (MAX)$	30	—	150	μA
I_{BHLS}	Bus Hold Low Sustaining Current	$V_{IN} = V_{IL} (MAX)$	30	—	—	μA
I_{BHHS}	Bus Hold High Sustaining Current	$V_{IN} = 0.7 V_{CCO}$	-30	—	—	μA
I_{BHLO}	Bus Hold Low Overdrive Current	$0 \leq V_{IN} \leq V_{IH} (MAX)$	—	—	150	μA
I_{BHHO}	Bus Hold High Overdrive Current	$0 \leq V_{IN} \leq V_{IH} (MAX)$	—	—	-150	μA
V_{BHT}	Bus Hold Trip Points		$V_{CCO} * 0.35$	—	$V_{CCO} * 0.65$	V
C_1	I/O Capacitance ³	$V_{CCO} = 3.3V, 2.5V, 1.8V$	—	8	—	pf
		$V_{CC} = 1.8V, V_{IO} = 0 \text{ to } V_{IH} (MAX)$	—		—	
C_2	Clock Capacitance ³	$V_{CCO} = 3.3V, 2.5V, 1.8V$	—	8	—	pf
		$V_{CC} = 1.8V, V_{IO} = 0 \text{ to } V_{IH} (MAX)$	—		—	
C_3	Global Input Capacitance ³	$V_{CCO} = 3.3V, 2.5V, 1.8V$	—	6	—	pf
		$V_{CC} = 1.8V, V_{IO} = 0 \text{ to } V_{IH} (MAX)$	—		—	

1. Input or I/O leakage current is measured with the pin configured as an input or as an I/O with the output driver tri-stated. It is not measured with the output driver active. Bus maintenance circuits are disabled.
2. 5V tolerant inputs and I/Os should be placed in banks where $3.0V \leq V_{CCO} \leq 3.6V$. The JTAG and sysCONFIG ports are not included for the 5V tolerant interface.
3. $T_A = 25^\circ C$, $f = 1.0MHz$.

ispXPGA 125B/C & ispXPGA 125EB/EC EBR Timing Parameters

Parameter	Description	-5 ¹		-4		-3		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
Synchronous Write								
t _{EBSWAD_S}	Address Setup Delay	0.59	—	0.61	—	0.70	—	ns
t _{EBSWAD_H}	Address Hold Delay	-0.40	—	-0.39	—	-0.33	—	ns
t _{EBSWCPW}	Clock Pulse Width	3.16	—	3.40	—	3.91	—	ns
t _{EBSWWE_S}	Write Enable Setup Time	-0.12	—	-0.12	—	-0.10	—	ns
t _{EBSWWE_H}	Write Enable Hold Time	0.16	—	0.16	—	0.18	—	ns
t _{EBSWD_S}	Data Setup Time	0.27	—	0.28	—	0.32	—	ns
t _{EBSWD_H}	Data Hold Time	-0.27	—	-0.26	—	-0.22	—	ns
Synchronous Read								
t _{EBSR_CO}	Clock to Data Delay	—	2.04	—	2.19	—	2.52	ns
t _{EBSRAD_S}	Address Setup Delay	0.10	—	0.10	—	0.12	—	ns
t _{EBSRAD_H}	Address Hold Delay	-0.07	—	-0.07	—	-0.06	—	ns
t _{EBSRCPW}	Clock Pulse Width	3.16	—	3.40	—	3.91	—	ns
t _{EBSRCE_S}	Clock Enable Setup Time	-1.76	—	-1.71	—	-1.45	—	ns
t _{EBSRCE_H}	Clock Enable Hold Time	1.64	—	1.69	—	1.94	—	ns
t _{EBSRWE_S}	Write Enable Setup Time	-0.18	—	-0.17	—	-0.14	—	ns
t _{EBSRWE_H}	Write Enable Hold Time	0.12	—	0.12	—	0.14	—	ns
t _{EBSRWEEN}	Write Enable to Data Enable Time	—	1.02	—	1.05	—	1.21	ns
t _{EBSRWEDIS}	Write Enable to Data Disable Time	—	0.99	—	1.02	—	1.17	ns
t _{EBSREN}	Output Enable to Data Enable Time	—	1.02	—	1.05	—	1.21	ns
t _{EBSRDIS}	Output Enable to Data Disable Time	—	0.83	—	0.86	—	0.99	ns
Asynchronous Read								
t _{EBARADO}	Address to New Valid Data Delay	—	2.39	—	2.46	—	2.83	ns
t _{EBARAD_H}	Address to Previous Valid Data Delay	—	2.10	—	2.17	—	2.50	ns
t _{EBARWEEN}	Write Enable to Data Enable Time	—	1.01	—	1.04	—	1.20	ns
t _{EBARWEDIS}	Write Enable to Data Disable Time	—	0.98	—	1.01	—	1.16	ns
t _{EBAREN}	Output Enable to Data Enable Time	—	1.02	—	1.05	—	1.21	ns
t _{EBARDIS}	Output Enable to Data Disable Time	—	0.83	—	0.86	—	0.99	ns

1. Only available for ispXPGA 125B and ispXPGA 125EB (2.5V/3.3V) devices.

Timing v.0.3

ispXPGA 125B/C & ispXPGA 125EB/EC Timing Adders

Parameter	Description	Base Parameter	-5 ¹		-4		-3		Units
			Min.	Max.	Min.	Max.	Min.	Max.	
Optional Adders									
t _{IOINDLY}	Input Delay	—	—	4.28	—	4.6	—	5.29	ns
t _{IOI} Input Adjusters									
LVTTL_in	Using 3.3V TTL	t _{IOIN}	—	0.5	—	0.5	—	0.5	ns
LVC MOS_18_in	Using 1.8V CMOS	t _{IOIN}	—	0.0	—	0.0	—	0.0	ns
LVC MOS_25_in	Using 2.5V CMOS	t _{IOIN}	—	0.3	—	0.3	—	0.3	ns
LVC MOS_33_in	Using 3.3V CMOS	t _{IOIN}	—	0.5	—	0.5	—	0.5	ns
AGP_1X_in	Using AGP 1x	t _{IOIN}	—	1.0	—	1.0	—	1.0	ns
CTT25_in	Using CTT 2.5V	t _{IOIN}	—	1.0	—	1.0	—	1.0	ns
CTT33_in	Using CTT 3.3V	t _{IOIN}	—	1.0	—	1.0	—	1.0	ns
GTL+_in	Using GTL+	t _{IOIN}	—	0.5	—	0.5	—	0.5	ns
HSTL_I_in	Using HSTL 2.5V, Class I	t _{IOIN}	—	0.5	—	0.5	—	0.5	ns
HSTL_III_in	Using HSTL 2.5V, Class III	t _{IOIN}	—	0.5	—	0.5	—	0.5	ns
LVDS_in	Using Low Voltage Differential Signaling (LVDS)	t _{IOIN}	—	0.8	—	0.8	—	0.8	ns
BLVDS_in	Using Bus Low Voltage Differential Signaling (BLVDS)	t _{IOIN}	—	0.8	—	0.8	—	0.8	ns
LVPECL_in	Using Low Voltage PECL	t _{IOIN}	—	0.8	—	0.8	—	0.8	ns
PCI_in	Using PCI	t _{IOIN}	—	1.0	—	1.0	—	1.0	ns
SSTL2_I_in	Using SSTL 2.5V, Class I	t _{IOIN}	—	0.8	—	0.8	—	0.8	ns
SSTL2_II_in	Using SSTL 2.5V, Class II	t _{IOIN}	—	0.5	—	0.5	—	0.5	ns
SSTL3_I_in	Using SSTL 3.3V, Class I	t _{IOIN}	—	0.8	—	0.8	—	0.8	ns
SSTL3_II_in	Using SSTL 3.3V, Class II	t _{IOIN}	—	0.8	—	0.8	—	0.8	ns
t _{IOO} Output Adjusters									
Slow Slew	Using Slow Slew (LVTTL and LVC MOS Outputs only)	t _{IOBUF} , t _{IOEN}	—	0.7	—	0.7	—	0.7	ns
LVTTL_out	Using 3.3V TTL Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	1.0	—	1.0	—	1.0	ns
LVC MOS_18_4mA_out	Using 1.8V CMOS Standard, 4mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.8	—	0.8	—	0.8	ns
LVC MOS_18_5.33mA_out	Using 1.8V CMOS Standard, 5.33mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.6	—	0.6	—	0.6	ns
LVC MOS_18_8mA_out	Using 1.8V CMOS Standard, 8mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.0	—	0.0	—	0.0	ns
LVC MOS_18_12mA_out	Using 1.8V CMOS Standard, 12mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.2	—	0.2	—	0.2	ns
LVC MOS_25_4mA_out	Using 2.5V CMOS Standard, 4mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.7	—	0.7	—	0.7	ns
LVC MOS_25_5.33mA_out	Using 2.5V CMOS Standard, 5.33 mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
LVC MOS_25_8mA_out	Using 2.5V CMOS Standard, 8mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
LVC MOS_25_12mA_out	Using 2.5V CMOS Standard, 12mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
LVC MOS_25_16mA_out	Using 2.5V CMOS Standard, 16mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns

ispXPGA 200B/C & ispXPGA 200EB/EC EBR Timing Parameters

Parameter	Description	-5 ¹		-4		-3		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
Synchronous Write								
t _{EBSWAD_S}	Address Setup Delay	0.59	—	0.61	—	0.70	—	ns
t _{EBSWAD_H}	Address Hold Delay	-0.40	—	-0.39	—	-0.33	—	ns
t _{EBSWCPW}	Clock Pulse Width	3.16	—	3.40	—	3.91	—	ns
t _{EBSWWE_S}	Write Enable Setup Time	-0.12	—	-0.12	—	-0.10	—	ns
t _{EBSWWE_H}	Write Enable Hold Time	0.16	—	0.16	—	0.18	—	ns
t _{EBSWD_S}	Data Setup Time	0.27	—	0.28	—	0.32	—	ns
t _{EBSWD_H}	Data Hold Time	-0.27	—	-0.26	—	-0.22	—	ns
Synchronous Read								
t _{EBSR_CO}	Clock to Data Delay	—	2.04	—	2.19	—	2.52	ns
t _{EBSRAD_S}	Address Setup Delay	0.10	—	0.10	—	0.12	—	ns
t _{EBSRAD_H}	Address Hold Delay	-0.07	—	-0.07	—	-0.06	—	ns
t _{EBSRCPW}	Clock Pulse Width	3.16	—	3.40	—	3.91	—	ns
t _{EBSRCE_S}	Clock Enable Setup Time	-1.76	—	-1.71	—	-1.45	—	ns
t _{EBSRCE_H}	Clock Enable Hold Time	1.64	—	1.69	—	1.94	—	ns
t _{EBSRWE_S}	Write Enable Setup Time	-0.18	—	-0.17	—	-0.14	—	ns
t _{EBSRWE_H}	Write Enable Hold Time	0.12	—	0.12	—	0.14	—	ns
t _{EBSRWEEN}	Write Enable to Data Enable Time	—	1.02	—	1.05	—	1.21	ns
t _{EBSRWEDIS}	Write Enable to Data Disable Time	—	0.99	—	1.02	—	1.17	ns
t _{EBSREN}	Output Enable to Data Enable Time	—	1.02	—	1.05	—	1.21	ns
t _{EBSRDIS}	Output Enable to Data Disable Time	—	0.83	—	0.86	—	0.99	ns
Asynchronous Read								
t _{EBARADO}	Address to New Valid Data Delay	—	2.39	—	2.46	—	2.83	ns
t _{EBARAD_H}	Address to Previous Valid Data Delay	—	2.10	—	2.17	—	2.50	ns
t _{EBARWEEN}	Write Enable to Data Enable Time	—	1.01	—	1.04	—	1.20	ns
t _{EBARWEDIS}	Write Enable to Data Disable Time	—	0.98	—	1.01	—	1.16	ns
t _{EBAREN}	Output Enable to Data Enable Time	—	1.02	—	1.05	—	1.21	ns
t _{EBARDIS}	Output Enable to Data Disable Time	—	0.83	—	0.86	—	0.99	ns

1. Only available for ispXPGA 200B and ispXPGA 200EB (2.5V/3.3V) devices.

Timing v.0.3

ispXPGA 200B/C & ispXPGA 200EB/EC Timing Adders

Parameter	Description	Base Parameter	-5 ¹		-4		-3		Units
			Min.	Max.	Min.	Max.	Min.	Max.	
Optional Adders									
t _{IOINDLY}	Input Delay	—	—	4.84	—	5.2	—	5.98	ns
t _{IOI} Input Adjusters									
LVTTL_in	Using 3.3V TTL	t _{IOIN}	—	0.5	—	0.5	—	0.5	ns
LVC MOS_18_in	Using 1.8V CMOS	t _{IOIN}	—	0.0	—	0.0	—	0.0	ns
LVC MOS_25_in	Using 2.5V CMOS	t _{IOIN}	—	0.3	—	0.3	—	0.3	ns
LVC MOS_33_in	Using 3.3V CMOS	t _{IOIN}	—	0.5	—	0.5	—	0.5	ns
AGP_1X_in	Using AGP 1x	t _{IOIN}	—	1.0	—	1.0	—	1.0	ns
CTT25_in	Using CTT 2.5V	t _{IOIN}	—	1.0	—	1.0	—	1.0	ns
CTT33_in	Using CTT 3.3V	t _{IOIN}	—	1.0	—	1.0	—	1.0	ns
GTL+_in	Using GTL+	t _{IOIN}	—	0.5	—	0.5	—	0.5	ns
HSTL_I_in	Using HSTL 2.5V, Class I	t _{IOIN}	—	0.5	—	0.5	—	0.5	ns
HSTL_III_in	Using HSTL 2.5V, Class III	t _{IOIN}	—	0.5	—	0.5	—	0.5	ns
LVDS_in	Using Low Voltage Differential Signaling (LVDS)	t _{IOIN}	—	0.8	—	0.8	—	0.8	ns
BLVDS_in	Using Bus Low Voltage Differential Signaling (BLVDS)	t _{IOIN}	—	0.8	—	0.8	—	0.8	ns
LVPECL_in	Using Low Voltage PECL	t _{IOIN}	—	0.8	—	0.8	—	0.8	ns
PCI_in	Using PCI	t _{IOIN}	—	1.0	—	1.0	—	1.0	ns
SSTL2_I_in	Using SSTL 2.5V, Class I	t _{IOIN}	—	0.8	—	0.8	—	0.8	ns
SSTL2_II_in	Using SSTL 2.5V, Class II	t _{IOIN}	—	0.5	—	0.5	—	0.5	ns
SSTL3_I_in	Using SSTL 3.3V, Class I	t _{IOIN}	—	0.8	—	0.8	—	0.8	ns
SSTL3_II_in	Using SSTL 3.3V, Class II	t _{IOIN}	—	0.8	—	0.8	—	0.8	ns
t _{IOO} Output Adjusters									
Slow Slew	Using Slow Slew (LVTTL and LVC MOS Outputs only)	t _{IOBUF} , t _{IOEN}	—	0.7	—	0.7	—	0.7	ns
LVTTL_out	Using 3.3V TTL Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	1.0	—	1.0	—	1.0	ns
LVC MOS_18_4mA_out	Using 1.8V CMOS Standard, 4mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.8	—	0.8	—	0.8	ns
LVC MOS_18_5.33mA_out	Using 1.8V CMOS Standard, 5.33mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.6	—	0.6	—	0.6	ns
LVC MOS_18_8mA_out	Using 1.8V CMOS Standard, 8mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.0	—	0.0	—	0.0	ns
LVC MOS_18_12mA_out	Using 1.8V CMOS Standard, 12mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.2	—	0.2	—	0.2	ns
LVC MOS_25_4mA_out	Using 2.5V CMOS Standard, 4mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.7	—	0.7	—	0.7	ns
LVC MOS_25_5.33mA_out	Using 2.5V CMOS Standard, 5.33 mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
LVC MOS_25_8mA_out	Using 2.5V CMOS Standard, 8mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
LVC MOS_25_12mA_out	Using 2.5V CMOS Standard, 12mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
LVC MOS_25_16mA_out	Using 2.5V CMOS Standard, 16mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns

ispXPGA 500B/C & ispXPGA 500EB/EC Timing Adders (Cont.)

Parameter	Description	Base Parameter	-5 ¹		-4		-3		Units
			Min.	Max.	Min.	Max.	Min.	Max.	
LVC MOS_33_4mA_out	Using 3.3V CMOS Standard, 4mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	1.0	—	1.0	—	1.0	ns
LVC MOS_33_5.33mA_out	Using 3.3V CMOS Standard, 5.33mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	1.0	—	1.0	—	1.0	ns
LVC MOS_33_8mA_out	Using 3.3V CMOS Standard, 8mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.7	—	0.7	—	0.7	ns
LVC MOS_33_12mA_out	Using 3.3V CMOS Standard, 12mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
LVC MOS_33_16mA_out	Using 3.3V CMOS Standard, 16mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
LVC MOS_33_24mA_out	Using 3.3V CMOS Standard, 24mA Drive	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
AGP_1X_out	Using AGP 1x Standard	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
CTT25_out	Using CTT 2.5V	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
CTT33_out	Using CTT 3.3V	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
GTL+_out	Using GTL+	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
HSTL_I_out	Using HSTL 2.5V, Class I	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
HSTL_III_out	Using HSTL 2.5V, Class III	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
LVDS_out	Using Low Voltage Differential Signaling (LVDS)	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	1.0	—	1.0	—	1.0	ns
BLVDS_out	Using Bus Low Voltage Differential Signaling (BLVDS)	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	1.0	—	1.0	—	1.0	ns
LVPECL_out	Using Low Voltage PECL	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	1.0	—	1.0	—	1.0	ns
PCI_out	Using PCI Standard	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
SSTL2_I_out	Using SSTL 2.5V, Class I	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
SSTL2_II_out	Using SSTL 2.5V, Class II	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
SSTL3_I_out	Using SSTL 3.3V, Class I	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns
SSTL3_II_out	Using SSTL 3.3V, Class II	t _{IOBUF} , t _{IOEN} , t _{IODIS}	—	0.5	—	0.5	—	0.5	ns

1. Only available for ispXPGA 500B and ispXPGA 500EB (2.5V/3.3V) devices.

Timing v.0.3

ispXPGA 1200B/C & ispXPGA 1200EB/EC External Switching Characteristics

Over Recommended Operating Conditions

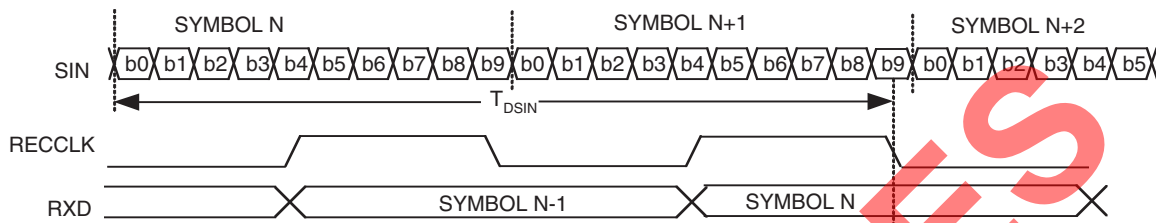
Parameter	Description	Conditions	-5 ¹		-4		-3		Units
			Min.	Max.	Min.	Max.	Min.	Max.	
t _{CO}	Global Clock Input to Output	PIO Output Register	—	6.6	—	7.1	—	8.2	ns
t _S	Global Clock Input Setup	PIO Input Register without input delay	-2.7	—	-2.7	—	-2.3	—	ns
t _H	Global Clock Input Hold	PIO Input Register without input delay	4.5	—	4.6	—	5.3	—	ns
t _{SINDLY}	Global Clock Input Setup	PIO Input Register with input delay	3.8	—	3.8	—	4.4	—	ns
t _{HINDLY}	Global Clock Input Hold	PIO Input Register with input delay	0.0	—	0.0	—	0.0	—	
t _{COPLL}	Global Clock Input to Output	PIO Output Register using PLL without delay	—	3.1	—	3.3	—	3.8	ns
t _{SPLL}	Global Clock Input Setup	PIO Input Register without input delay using PLL without delay	0.5	—	0.5	—	0.6	—	ns
t _{HPLL}	Global Clock Input Hold	PIO Input Register without input delay using PLL without delay	0.8	—	0.8	—	1.0	—	ns
t _{SINDLYPLL}	Global Clock Input Setup	PIO Input Register with input delay using PLL without delay	7.6	—	7.6	—	8.8	—	ns
t _{HINDLYPLL}	Global Clock Input Hold	PIO Input Register with input delay using PLL without delay	-4.1	—	-4.0	—	-3.4	—	ns

1. Only available for ispXPGA 1200B and ispXPGA 1200EB (2.5V/3.3V) devices.

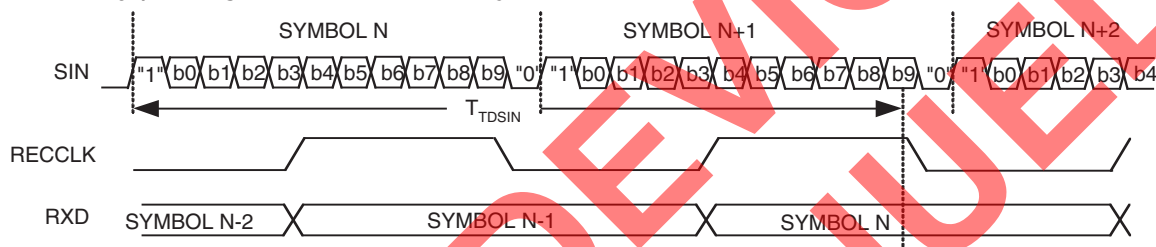
Timing v.0.2

Deserializer Timing

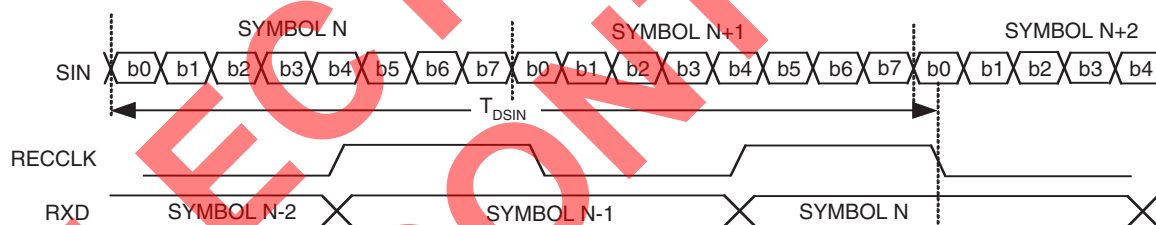
8B/10B DESERIALIZER DELAY TIMING



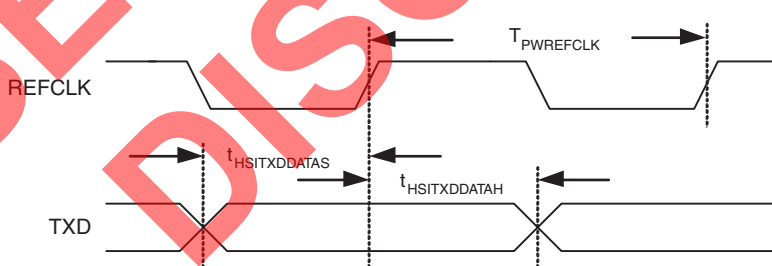
10B/12B DESERIALIZER DELAY TIMING



CDRX_SS DESERIALIZER DELAY TIMING



INTERNAL TIMING FOR sysHSI BLOCK



sysCLOCK PLL Timing

Over Recommended Operating Conditions

Symbol	Parameter	Conditions	Min	Max	Units
t_{PWH}	Input clock, high time	80% to 80%	1.2	—	ns
t_{PWL}	Input clock, low time	20% to 20%	1.2	—	ns
t_R, t_F	Input Clock, rise and fall time	20% to 80%	—	3.0	ns
t_{INSTB}	Input clock stability, cycle to cycle (peak)		—	+/- 250	ps
f_{MDIVIN}	M Divider input, frequency range		10	320	MHz
$f_{MDIVOUT}$	M Divider output, frequency range		10	320	MHz
f_{NDIVIN}	N Divider input, frequency range		10	320	MHz
$f_{NDIVOUT}$	N Divider output, frequency range		10	320	MHz
f_{VDIVIN}	V Divider input, frequency range		100	400	MHz
$f_{VDIVOUT}$	V Divider output, frequency range		10	320	MHz
$t_{OUTDUTY}$	output clock, duty cycle		40	60	%
$t_{JIT(CC)}$	Output clock, cycle to cycle jitter (peak)	Clean reference ¹ 10MHz δ $f_{MDIVOUT}$ δ 40MHz or 100MHz δ f_{VDIVIN} δ 160MHz	—	+/- 600	ps
		Clean reference ¹ 40MHz δ $f_{MDIVOUT}$ δ 320MHz and 160MHz δ f_{VDIVIN} δ 400MHz	—	+/- 150	ps
$t_{JIT(PER)}^2$	Output clock, period jitter (peak)	Clean reference ¹ 10MHz δ $f_{MDIVOUT}$ δ 40MHz or 100MHz δ f_{VDIVIN} δ 160MHz	—	+/- 600	ps
		Clean reference ¹ 40MHz δ $f_{MDIVOUT}$ δ 320MHz and 160MHz δ f_{VDIVIN} δ 400MHz	—	+/- 150	ps
$t_{CLK_OUT_DELAY}$	Input clock to CLK_OUT delay	Internal feedback	—	3.0	ns
t_{PHASE}	Input clock to external feedback delta	External feedback	—	1.5	ns
t_{LOCK}	Time to acquire phase lock after input stable		—	25	us
t_{PLL_DELAY}	Delay increment (Lead/Lag)	Typical = +/- 250ps	+/- 120	+/- 550	ps
t_{RANGE}	Total output delay range (lead/lag)		+/- 0.84	+/- 3.85	ns
t_{PLL_RSTW}	Minimum reset pulse width		1.8	—	ns
$t_{CLK_IN}^3$	Global clock input delay		—	1.0	ns
$t_{PLL_SEC_DELAY}$	Secondary PLL output delay		—	1.5	ns

1. This condition assures that the output phase jitter will remain within specifications. Jitter spec is based on optimized M, N and V settings determined by the ispLEVER software.

2. Accumulated jitter measured over 10,000 waveform samples

3. Internal timing for reference only.

ispXPGA Logic Signal Connections: 256-Ball fpBGA (Cont.)

256-fpBGA Ball	LFX200			LFX125		
	Signal Name	Second Function	LVDS Pair/ sysHSI Reserved ²	Signal Name	Second Function	LVDS Pair/ sysHSI Reserved ²
D16	BK5_IO15	HSI3A_SOUTN	72N/HSI3	BK5_IO13	HSI1A_SOUTN	61N/HSI1
E13	BK5_IO16	VREF5	73P/HSI3	BK5_IO14	VREF5	62P/HSI1
E14	BK5_IO17	-	73N/HSI3	BK5_IO15	-	62N/HSI1
E15	BK5_IO18	HSI3B_SINP	74P/HSI3	BK5_IO16	HSI1B_SINP	63P/HSI1
-	-	-	-	GND (Bank 5)	-	-
D15	BK5_IO19	HSI3B_SINN	74N/HSI3	BK5_IO17	HSI1B_SINN	63N/HSI1
C16	BK5_IO22	HSI3B_SOUTP	76P/HSI3	BK5_IO20	HSI1B_SOUTP	65P/HSI1
-	GND (Bank 5)	-	-	-	-	-
B16	BK5_IO23	HSI3B_SOUTN	76N/HSI3	BK5_IO21	HSI1B_SOUTN	65N/HSI1
D14	BK5_IO24	-	77P/HSI3	BK5_IO18	-	64P/HSI1
C15	BK5_IO25	-	77N/HSI3	BK5_IO19	-	64N/HSI1
C13	CFG0	-	-	CFG0	-	-
A15	DONE	-	-	DONE	-	-
A14	PROGRAMb	-	-	PROGRAMb	-	-
D12	BK6_IO0	INITb	78P	BK6_IO0	INITb	66P
C12	BK6_IO1	CCLK	78N	BK6_IO1	CCLK	66N
B14	BK6_IO2	-	79P	BK6_IO2	-	67P
-	GND (Bank 6)	-	-	-	-	-
B13	BK6_IO3	-	79N	BK6_IO3	-	67N
A13	BK6_IO4	CSb	80P	BK6_IO4	CSb	68P
-	-	-	-	GND (Bank 6)	-	-
A12	BK6_IO5	Read	80N	BK6_IO5	READ	68N
D11	BK6_IO6	DATA7	81P	BK6_IO6	DATA7	69P
C11	BK6_IO7	DATA6	81N	BK6_IO7	DATA6	69N
B12	BK6_IO8	-	82P	BK6_IO8	-	70P
B11	BK6_IO9	VREF6	82N	BK6_IO9	VREF6	70N
D10	BK6_IO10	DATA5	83P	BK6_IO10	DATA5	71P
-	GND (Bank 6)	-	-	-	-	-
C10	BK6_IO11	DATA4	83N	BK6_IO11	DATA4	71N
-	-	-	-	GND (Bank 6)	-	-
A11	BK6_IO14	DATA3	85P	BK6_IO14	DATA3	73P
A10	BK6_IO15	DATA2	85N	BK6_IO15	DATA2	73N
D9	BK6_IO16	-	86P	BK6_IO16	-	74P
C9	BK6_IO17	-	86N	BK6_IO17	-	74N
B10	BK6_IO18	DATA1	87P	BK6_IO18	DATA1	75P
-	GND (Bank 6)	-	-	GND (Bank 6)	-	-
B9	BK6_IO19	DATA0	87N	BK6_IO19	DATA0	75N
E9	BK6_IO20	-	88P	BK6_IO20	-	76P
E8	BK6_IO21	-	88N	BK6_IO21	-	76N
-	GND (Bank 6)	-	-	-	-	-
-	GND (Bank 7)	-	-	-	-	-
D8	BK7_IO0	-	91P	BK7_IO0	-	77P

ispXPGA Logic Signal Connections: 516-Ball fpBGA (Cont.)

516-Ball BGA Ball	LFX500			LFX200			LFX125		
	Signal Name	Second Function	LVDS Pair/ sysHSI Reserved ¹	Signal Name	Second Function	LVDS Pair/ sysHSI Reserved ¹	Signal Name	Second Function	LVDS Pair/ sysHSI Reserved ¹
AE3	BK1_IO33	-	37N/HSI2	NC	-	-	NC	-	-
AG1	BK1_IO34	-	38P/HSI2	NC	-	-	NC	-	-
AH1	BK1_IO35	-	38N/HSI2	NC	-	-	NC	-	-
AG2	BK1_IO36	-	39P/HSI2	NC	-	-	NC	-	-
AF3	BK1_IO37	-	39N/HSI2	NC	-	-	NC	-	-
AJ1	BK1_IO38	-	40P/HSI2	NC	-	-	NC	-	-
-	GND (Bank 1)	-	-	-	-	-	-	-	-
AH2	BK1_IO39	-	40N/HSI2	NC	-	-	NC	-	-
AG3	BK1_IO40	-	41P	BK1_IO24	-	25P/HSI1	NC	-	-
AF4	BK1_IO41	-	41N	BK1_IO25	-	25N/HSI1	NC	-	-
AK2	TCK	-	-	TCK	-	-	TCK	-	-
AJ3	TMS	-	-	TMS	-	-	TMS	-	-
AG5	TOE	-	-	TOE	-	-	TOE	-	-
AH4	BK2_IO0	-	42P	BK2_IO0	-	26P	BK2_IO0	-	22P
AK3	BK2_IO1	-	42N	BK2_IO1	-	26N	BK2_IO1	-	22N
AJ4	BK2_IO2	-	43P	BK2_IO2	-	27P	BK2_IO2	-	23P
-	GND (Bank 2)	-	-	GND (Bank 2)	-	-	-	-	-
AH5	BK2_IO3	-	43N	BK2_IO3	-	27N	BK2_IO3	-	23N
AK4	BK2_IO4	-	44P	BK2_IO4	-	28P	BK2_IO4	-	24P
-	-	-	-	-	-	-	GND (Bank 2)	-	-
AJ5	BK2_IO5	-	44N	BK2_IO5	-	28N	BK2_IO5	-	24N
AG7	BK2_IO6	-	45P	BK2_IO6	-	29P	BK2_IO6	-	25P
AH6	BK2_IO7	-	45N	BK2_IO7	-	29N	BK2_IO7	-	25N
AK5	BK2_IO8	-	46P	NC	-	-	NC	-	-
AJ6	BK2_IO9	-	46N	NC	-	-	NC	-	-
AG8	BK2_IO10	-	47P	NC	-	-	NC	-	-
-	GND (Bank 2)	-	-	-	-	-	-	-	-
AH7	BK2_IO11	-	47N	NC	-	-	NC	-	-
AK6	BK2_IO12	-	48P	NC	-	-	NC	-	-
AJ7	BK2_IO13	-	48N	NC	-	-	NC	-	-
AH8	BK2_IO14	-	49P	NC	-	-	NC	-	-
AG10	BK2_IO15	-	49N	NC	-	-	NC	-	-
AK7	BK2_IO16	-	50P	NC	-	-	NC	-	-
AJ8	BK2_IO17	-	50N	NC	-	-	NC	-	-
AH9	BK2_IO18	-	51P	NC	-	-	NC	-	-
-	GND (Bank 2)	-	-	-	-	-	-	-	-
AG11	BK2_IO19	-	51N	NC	-	-	NC	-	-
AK8	BK2_IO20	-	52P	BK2_IO8	-	30P	BK2_IO8	-	26P
AJ9	BK2_IO21	VREF2	52N	BK2_IO9	VREF2	30N	BK2_IO9	VREF2	26N
AH10	BK2_IO22	-	53P	BK2_IO10	-	31P	BK2_IO10	-	27P
-	-	-	-	GND (Bank 2)	-	-	-	-	-
AH11	BK2_IO23	-	53N	BK2_IO11	-	31N	BK2_IO11	-	27N
AJ10	BK2_IO24	-	54P	BK2_IO12	-	32P	BK2_IO12	-	28P
AK10	BK2_IO25	-	54N	BK2_IO13	-	32N	BK2_IO13	-	28N
AH12	BK2_IO26	-	55P	BK2_IO14	-	33P	BK2_IO14	-	29P
-	GND (Bank 2)	-	-	-	-	-	-	-	-
AJ11	BK2_IO27	-	55N	BK2_IO15	-	33N	BK2_IO15	-	29N
AK11	BK2_IO28	-	56P	NC	-	-	NC	-	-
AJ12	BK2_IO29	-	56N	NC	-	-	NC	-	-
AG13	BK2_IO30	-	57P	BK2_IO16	-	34P	BK2_IO16	-	30P
AH13	BK2_IO31	-	57N	BK2_IO17	-	34N	BK2_IO17	-	30N

ispXPGA Logic Signal Connections: 680-Ball fpBGA (Cont.)

LFX1200			
680-Ball fpBGA	Signal Name	Second Function	LVDS Pair/sysHSI Reserved ¹
C24	BK1_IO7	SS_CLKIN0N	34N
A22	BK1_IO8	-	35P
D22	BK1_IO9	-	35N
A23	BK1_IO10	-	36P
-	GND (Bank 1)	-	-
B25	BK1_IO11	-	36N
D23	BK1_IO12	PLL_RST2	37P
A24	BK1_IO13	PLL_RST3	37N
A25	BK1_IO14	-	38P
E24	BK1_IO15	-	38N
D24	BK1_IO16	-	39P
A26	BK1_IO17	-	39N
D25	BK1_IO18	-	40P
-	GND (Bank 1)	-	-
C25	BK1_IO19	-	40N
B26	BK1_IO20	-	41P/HSI3
B27	BK1_IO21	-	41N/HSI3
D26	BK1_IO22	-	42P/HSI3
A27	BK1_IO23	-	42N/HSI3
A28	BK1_IO24	-	43P/HSI3
E26	BK1_IO25	-	43N/HSI3
C27	BK1_IO26	HSI3A_SOUTP	44P/HSI3
-	GND (Bank 1)	-	-
D27	BK1_IO27	HSI3A_SOUTN	44N/HSI3
B28	BK1_IO28	-	45P/HSI3
A30	BK1_IO29	-	45N/HSI3
C28	BK1_IO30	HSI3A_SINP	46P/HSI3
D28	BK1_IO31	HSI3A_SINN	46N/HSI3
A31	BK1_IO32	-	47P/HSI3
B30	BK1_IO33	-	47N/HSI3
E28	BK1_IO34	HSI3B_SOUTP	48P/HSI3
-	GND (Bank 1)	-	-
D29	BK1_IO35	HSI3B_SOUTN	48N/HSI3
C29	BK1_IO36	-	49P/HSI4
B31	BK1_IO37	-	49N/HSI4
D30	BK1_IO38	HSI3B_SINP	50P/HSI4
E30	BK1_IO39	HSI3B_SINN	50N/HSI4
A32	BK1_IO40	-	51P/HSI4
C31	BK1_IO41	-	51N/HSI4
D31	BK1_IO42	HSI4A_SOUTP	52P/HSI4
-	GND (Bank 1)	-	-
C32	BK1_IO43	HSI4A_SOUTN	52N/HSI4
B32	BK1_IO44	-	53P/HSI4

ispXPGA Logic Signal Connections: 900-Ball fpBGA (Cont.)

900 fpBGA Ball	LFX1200			LFX500		
	Signal Name	Second Function	LVDS Pair/ sysHSI Reserved ¹	Signal Name	Second Function	LVDS Pair/ sysHSI Reserved ¹
AJ18	BK3_IO14	-	100P	BK3_IO14	-	70P
-	-	-	-	GND (Bank 3)	-	-
AK18	BK3_IO15	-	100N	BK3_IO15	-	70N
AE18	BK3_IO16	-	101P	BK3_IO16	-	71P
AD18	BK3_IO17	-	101N	BK3_IO17	-	71N
AJ19	BK3_IO18	-	102P	BK3_IO18	-	72P
-	GND (Bank 3)	-	-	-	-	-
AK19	BK3_IO19	-	102N	BK3_IO19	-	72N
AH19	BK3_IO20	-	103P	NC	-	-
AG19	BK3_IO21	-	103N	NC	-	-
AK20	BK3_IO22	-	104P	NC	-	-
AJ20	BK3_IO23	-	104N	NC	-	-
AF19	BK3_IO24	-	105P	NC	-	-
AE19	BK3_IO25	-	105N	NC	-	-
AH20	BK3_IO26	-	106P	NC	-	-
-	GND (Bank 3)	-	-	-	-	-
AG20	BK3_IO27	-	106N	NC	-	-
AF20	BK3_IO28	-	107P	NC	-	-
AE20	BK3_IO29	-	107N	NC	-	-
AJ21	BK3_IO30	-	108P	NC	-	-
AK21	BK3_IO31	-	108N	NC	-	-
AG21	BK3_IO32	-	109P	NC	-	-
AF21	BK3_IO33	-	109N	NC	-	-
AK22	BK3_IO34	-	110P	NC	-	-
-	GND (Bank 3)	-	-	-	-	-
AJ22	BK3_IO35	-	110N	NC	-	-
AE21	BK3_IO36	-	111P	NC	-	-
AD21	BK3_IO37	-	111N	NC	-	-
AG22	BK3_IO38	-	112P	NC	-	-
AF22	BK3_IO39	-	112N	NC	-	-
AG23	BK3_IO40	-	113P	BK3_IO22	-	74P
-	-	-	-	GND (Bank 3)	-	-
AH23	BK3_IO41	-	113N	BK3_IO23	-	74N
AJ23	BK3_IO42	-	114P	BK3_IO24	-	75P
-	GND (Bank 3)	-	-	-	-	-
AK23	BK3_IO43	-	114N	BK3_IO25	-	75N
AF23	BK3_IO44	-	115P	BK3_IO26	-	76P
AE23	BK3_IO45	-	115N	BK3_IO27	-	76N
AJ24	BK3_IO46	-	116P	BK3_IO28	-	77P
AK24	BK3_IO47	-	116N	BK3_IO29	-	77N
AH24	BK3_IO48	-	117P	BK3_IO21	-	73N
AG24	BK3_IO49	VREF3	117N	BK3_IO20	VREF3	73P

ispXPGA Logic Signal Connections: 900-Ball fpBGA (Cont.)

900 fpBGA Ball	LFX1200			LFX500		
	Signal Name	Second Function	LVDS Pair/ sysHSI Reserved ¹	Signal Name	Second Function	LVDS Pair/ sysHSI Reserved ¹
B15	BK7_IO1	-	217N	BK7_IO1	-	147N
C15	BK7_IO2	-	218P	BK7_IO2	-	148P
-	GND (Bank 7)	-	-	-	-	-
D15	BK7_IO3	-	218N	BK7_IO3	-	148N
E15	BK7_IO4	-	219P	BK7_IO4	-	149P
F15	BK7_IO5	-	219N	BK7_IO5	-	149N
A14	BK7_IO6	-	220P	BK7_IO6	-	150P
-	-	-	-	GND (Bank 7)	-	-
B14	BK7_IO7	-	220N	BK7_IO7	-	150N
C14	BK7_IO8	-	221P	BK7_IO8	-	151P
D14	BK7_IO9	-	221N	BK7_IO9	-	151N
E14	BK7_IO10	-	222P	BK7_IO10	-	152P
-	GND (Bank 7)	-	-	-	-	-
F14	BK7_IO11	-	222N	BK7_IO11	-	152N
C13	BK7_IO12	-	223P	BK7_IO12	-	153P
D13	BK7_IO13	-	223N	BK7_IO13	-	153N
B13	BK7_IO14	-	224P	BK7_IO14	-	154P
-	-	-	-	GND (Bank 7)	-	-
A13	BK7_IO15	-	224N	BK7_IO15	-	154N
F13	BK7_IO16	-	225P	BK7_IO16	-	155P
G13	BK7_IO17	-	225N	BK7_IO17	-	155N
A12	BK7_IO18	-	226P	BK7_IO18	-	156P
-	GND (Bank 7)	-	-	-	-	-
B12	BK7_IO19	-	226N	BK7_IO19	-	156N
C12	BK7_IO20	-	227P	NC	-	-
D12	BK7_IO21	-	227N	NC	-	-
A11	BK7_IO22	-	228P	NC	-	-
B11	BK7_IO23	-	228N	NC	-	-
E12	BK7_IO24	-	229P	NC	-	-
F12	BK7_IO25	-	229N	NC	-	-
C11	BK7_IO26	-	230P	NC	-	-
-	GND (Bank 7)	-	-	-	-	-
D11	BK7_IO27	-	230N	NC	-	-
E11	BK7_IO28	-	231P	NC	-	-
F11	BK7_IO29	-	231N	NC	-	-
B10	BK7_IO30	-	232P	NC	-	-
A10	BK7_IO31	-	232N	NC	-	-
D10	BK7_IO32	-	233P	NC	-	-
E10	BK7_IO33	-	233N	NC	-	-
A9	BK7_IO34	-	234P	NC	-	-
-	GND (Bank 7)	-	-	-	-	-
B9	BK7_IO35	-	234N	NC	-	-

“E-Series” Industrial (Cont.)

Part Number	Gates	Voltage	Speed Grade	Package	Balls
LFX1200EB-04F900I ²	1.25M	2.5/3.3	-4	fpBGA	900
LFX1200EB-03F900I ²	1.25M	2.5/3.3	-3	fpBGA	900
LFX1200EC-03F900I ²	1.25M	1.8	-3	fpBGA	900
LFX1200EB-04FE680I ²	1.25M	2.5/3.3	-4	fpSBGA	680
LFX1200EB-03FE680I ²	1.25M	2.5/3.3	-3	fpSBGA	680
LFX1200EC-03FE680I ²	1.25M	1.8	-3	fpSBGA	680

1. FH516 package was converted to F516 via [PCN #09A-08](#).

2. Discontinued via [PCN #03A-10](#).

Lead-Free Packaging

Commercial

Part Number	Gates	Voltage	Speed Grade	Package	Balls
LFX125B-05FN256C	139K	2.5/3.3	-5	Lead-Free fpBGA	256
LFX125B-04FN256C	139K	2.5/3.3	-4	Lead-Free fpBGA	256
LFX125B-03FN256C	139K	2.5/3.3	-3	Lead-Free fpBGA	256
LFX125C-04FN256C	139K	1.8	-4	Lead-Free fpBGA	256
LFX125C-03FN256C	139K	1.8	-3	Lead-Free fpBGA	256
LFX200B-05FN256C	210K	2.5/3.3	-5	Lead-Free fpBGA	256
LFX200B-04FN256C	210K	2.5/3.3	-4	Lead-Free fpBGA	256
LFX200B-03FN256C	210K	2.5/3.3	-3	Lead-Free fpBGA	256
LFX200C-04FN256C	210K	1.8	-4	Lead-Free fpBGA	256
LFX200C-03FN256C	210K	1.8	-3	Lead-Free fpBGA	256
LFX500B-05FN900C	476K	2.5/3.3	-5	Lead-Free fpBGA	900
LFX500B-04FN900C	476K	2.5/3.3	-4	Lead-Free fpBGA	900
LFX500B-03FN900C	476K	2.5/3.3	-3	Lead-Free fpBGA	900
LFX500C-04FN900C	476K	1.8	-4	Lead-Free fpBGA	900
LFX500C-03FN900C	476K	1.8	-3	Lead-Free fpBGA	900

“E-Series” Commercial

Part Number	Gates	Voltage	Speed Grade	Package	Balls
LFX125EB-05FN256C	139K	2.5/3.3	-5	Lead-Free fpBGA	256
LFX125EB-04FN256C	139K	2.5/3.3	-4	Lead-Free fpBGA	256
LFX125EB-03FN256C	139K	2.5/3.3	-3	Lead-Free fpBGA	256
LFX125EC-04FN256C	139K	1.8	-4	Lead-Free fpBGA	256
LFX125EC-03FN256C	139K	1.8	-3	Lead-Free fpBGA	256
LFX200EB-05FN256C	210K	2.5/3.3	-5	Lead-Free fpBGA	256
LFX200EB-04FN256C	210K	2.5/3.3	-4	Lead-Free fpBGA	256
LFX200EB-03FN256C	210K	2.5/3.3	-3	Lead-Free fpBGA	256
LFX200EC-04FN256C	210K	1.8	-4	Lead-Free fpBGA	256
LFX200EC-03FN256C	210K	1.8	-3	Lead-Free fpBGA	256
LFX500EB-05FN900C	476K	2.5/3.3	-5	Lead-Free fpBGA	900
LFX500EB-04FN900C	476K	2.5/3.3	-4	Lead-Free fpBGA	900
LFX500EB-03FN900C	476K	2.5/3.3	-3	Lead-Free fpBGA	900

Revision History (Cont.)

Date	Version	Change Summary
June 2004 (cont.)	08.0 (cont.)	Updated Global Clock Input Setup time specifications.
		Clarification of Serial Out LVDS test condition.
		Clarification of REFCLK, SS_CLKIN peak-to-peak period jitter condition.
		Added sysHSI Reserved pins and footnote.
		Removed industrial ordering part numbers.
July 2004	09.0	Added "E" Series product family.
August 2004	10.0	Final release.
December 2004	10.1	Updated NC Connections table.
April 2005	10.2	Clarification of IDK specification.
April 2005	11.0	Select lead-free packages release.
July 2005	12.0	Added lead-free 516 fpBGA ordering part numbers.
April 2007	13.0	Removed lead-free 680 fpSBGA information from Part Number Description and Ordering Part Number tables. Removed lead-free 516 fpBGA for LFX125 from Ordering Part Number tables.
November 2007	14.0	Removed lead-free 516 fpBGA information from Part Number Description and Ordering Part Number tables.
July 2008	14.1	Added 516 fpBGA package without heat spreader to Part Number Description and Ordering Part Number tables.
February 2010	15.0	Ordering part numbers and ispXPGA Family Selection Guide table have been updated per PCN #03A-10 (discontinuation of the ispXPGA 1200 devices).
		References to "system gates" changed to "functional gates."